

# Qucs Roadmap: background to the new features in release 0.0.18 and an outline of future software development directions

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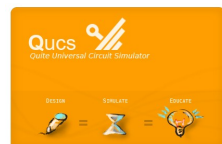
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Plus contributions from Developers in the Qucs user community.

**Listed in “Projects of the week”, September 8, 2014, by Sourceforge.**

- **Qucs release 0.0.18: an overview of new simulation and compact device modelling features**
- **Compact model development with the Qucs/ADMS “Turn-key” modelling system**
- **Qucs experimental implementation of the BSIM 6.1 MOS transistor model**
- **Model parameter extraction: linking Qucs with low-cost measurement instrumentation; RF components**
- **Qucs swept Harmonic Balance simulation: Verilog-A and EDD diode models**
- **Current and possible future directions for Qucs development**

Presented by Wlodek Grabinski on behalf of the “Qucs Development Team” at the MOS-AK Workshop,  
Berkeley, December 12, 2014



# Qucs release 0.0.18: an overview of new simulation and compact device modelling features

Qucs 0.0.18 was released at the end of August 2014. It can be downloaded from the Sourceforge.net web site in binary and source code. The 0.0.18 release is available as binary ready to run code for the Linux (Ubuntu), MAC OSX (Darwin) and Windows (XP, 7, 8 and 8.1) operating systems.

## Qucs 0.0.18 Release Notes

This release brings improvements to many parts of Qucs. The port from Qt3 to Qt4 is still ongoing and many bugs and usability issues have been fixed in the process. A few new features were added and others are in development. See below a short summary of the most noticeable enhancements. Qucs and Qucsator.

- **new:** Dynamic compilation and loading of Verilog-A modules (beta feature). Addition of a full ADMS/Qucs "turn key" Verilog-A compact device modelling system to Qucs. Users are no longer required to manually edit C++ code and the build system to be able to run Verilog-A models. Uses ADMS 2.3.4 (only a subset of Verilog-A is supported).
- **fix:** Spice file handling and translator.
- **new:** Addition of BSIM 3 and BSIM 4 models to Qucs MOS models.
- **new:** Release of the first model (RFresistor) in a new series of RF models for Harmonic Balance and other forms of Qucs simulation.
- **new:** HICUM npn and pnp Level 0 V1.3 Verilog-A devices.
- **new:** HICUM npn level 2 V2.32 Verilog-A device.



# Qucs 0.0.18 release

## Qucs

- **new/fix** : Ported several classes from Qt3 Support to Qt4 (work in progress).
- **new**: use QSettings to store user preferences and application settings.
- **new**: Copy/duplicate project content files.
- **new**: Export schematic and diagrams to SVG, PNG, JPG, JPEG, PDF, PDF+Latex, EPS (Inkscape required).
- **new**: Component library is not included on the Dock Window.
- **new**: Added checkbox to settings, which allows to load schematics from future versions.
- **new**: Open Recent menu option.
- **new**: Set ADMS, ASCO and Octave paths on the application settings.
- **new**: Use environment variables ADMSXMLBINDIR, ASCOBINDIR, OCTAVEBINDIR to set tools paths.
- **new**: Updated translations: pt-BR, pt-PT, ru.

## Qucsator

- **new**: Refactoring of Qucsator namespace. Most of the core functions are under the namespace qucs::
- **new**: Allow to run autotest by adding bugon/assert operator.
- **new**: initial support for unit testing with googletest.
- **new**: added a Python scripts for parsing Qucs data files.
- **fix**: enable BJT models with ( $V_{tf} < 0$ ).

## QucsFilter, QucsAttenuator, QucsHelp, QucsEdit

- **new/fix** : Ported several classes from Qt3Support to Qt4 (work in progress)

## QucsResCodes

- **new**: QucsResCodes is a program to compute color codes for resistors and resistance values from color codes. The program computes the closest standard resistor value. Users can paste the computed resistor in the schematic.



# Qucs 0.0.18 release

## Interfaces

- Improved Qucs/Octave interface for GUI and Qucssator netlist entry (including a start on a Octave library of plotting functions for Qucs post simulation data visualisation).
- First steps in developing a combined Qucs/Python Qucs simulation capability with high quality data visualisation using matplotlib. Applications include basic sensitivity analysis and circuit performance optimisation.
- Preliminary version of Qucs/Octave linked transient simulation capability.

## Build system

- Add ADMS as a Git submodule to the Qucs Git repository.
- Added --disable-asco and --disable-adms option to skip the build of included sources.
- Added CMake (experimental) for advanced users building from Git repository.
- OSX: options to build against 10.5 to 10.9 SDK.
- Included packages: ASCO 0.4.9 (patched) and ADMS 2.3.4.

## Miscellaneous

- Project website is now under version control.
- Source code is now under Travis continuous integration service.
- Source code documentation (Doxygen) available on the website.
- Preliminary regression and test suite (qucs-test).

## • Bug fixes

- Hundreds of bug fixes and code improvements.



# Compact model development with the Qucs/ADMS “Turn-key” modelling system: 1. Build Verilog-A module

The screenshot shows the Qucs 0.0.18 interface. On the left, the 'Project Content' tree is expanded to 'Verilog-A', showing the file 'bsim6MOD.va'. The main editor displays the Verilog-A code for 'bsim6MOD.va', which includes includes for 'constants.vams' and 'disciplines.vams', and defines various macros for performance optimization and pinchoff voltage calculation. At the bottom, the console window shows the output of the ADMS compiler, including warnings and file creation messages. The status bar at the bottom indicates that 'admsXml' and 'Compiler' are active.

Select from Project drop-down menu

“Build Verilog-A module”

ADMS compiles XXX.va to C++ code

C++ code compiled and linked to Qucs



# Compact model development with the Qucs/ADMS “Turn-key” modelling system: 2. Edit text symbol

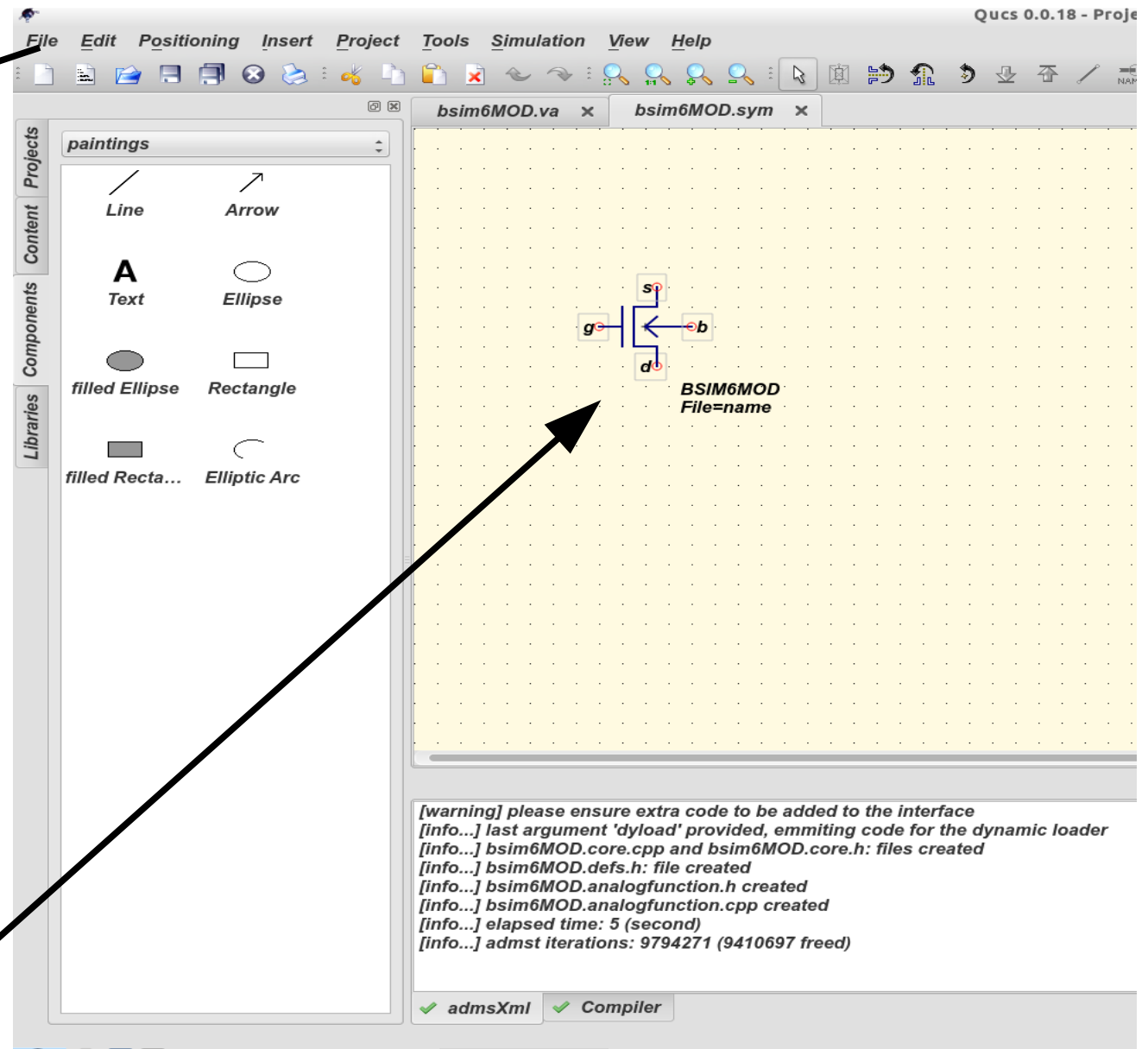
Select from File drop-down menu [with xxx.va code displayed]

“Edit text symbol”

Qucs displays symbol template

EDIT

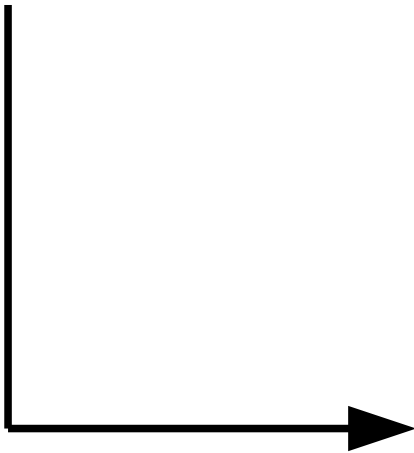
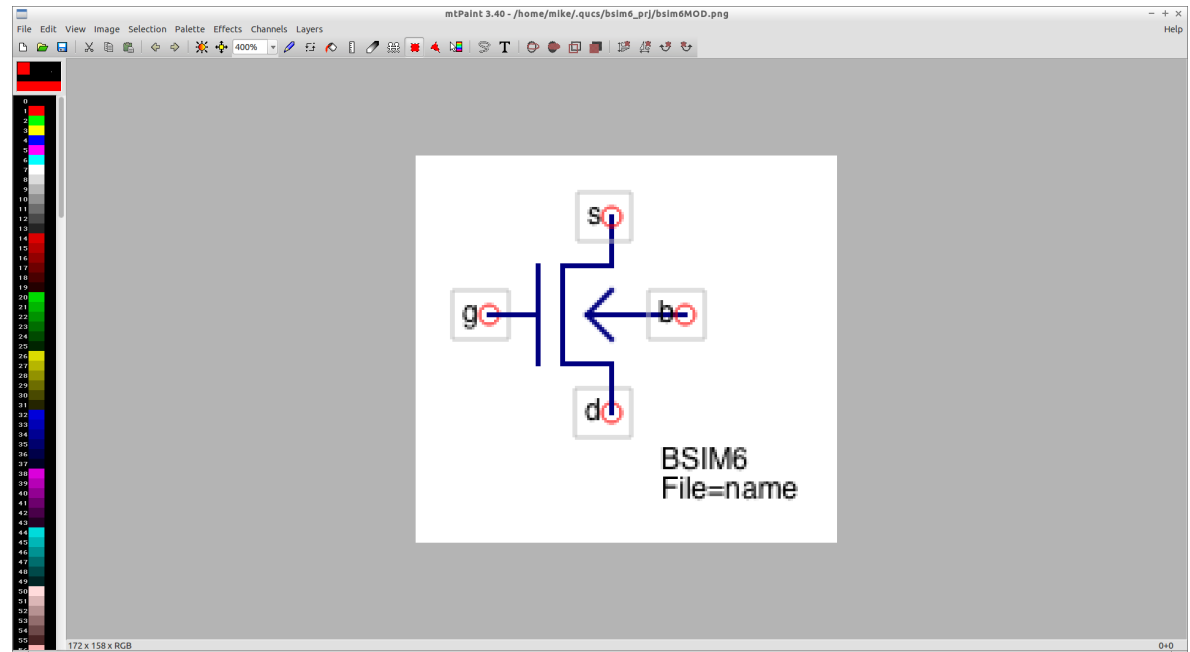
Then save to current project



# Compact model development with the Qucs/ADMS “Turn-key” modelling system: 3. Generate and add icon to current project

Generate icon bitmap file

XXXX.png



Save XXXX.png file in working project,  
For example BSIM6MOD\_prj



# Compact model development with the Qucs/ADMS “Turn-key” modelling system: 4. Load new model before use

Select from Project drop-down menu  
↓  
“Load Verilog-A module”  
↓  
Load Verilog-A Symbol file(s)

The screenshot displays the Qucs/ADMS software interface. On the left, the 'Libraries' panel shows various components under 'lumped components'. The central workspace is titled 'untitled'. A dialog box titled 'Load Verilog-A symbols' is open, prompting the user to 'Choose Verilog-A symbol files:'. The file 'bsim6MOD\_symbol.json' is selected. Below the file list are buttons for 'Select All', 'Deselect All', 'Cancel', and 'Ok'. The right-hand panel shows the 'verilog-a user devices' library with 'bsim6MOD' added. The status bar at the bottom indicates 'admsXml' and 'Compiler' are active.

```
[warning] please ensure extra code to be added to the interface
[info...] last argument 'dyload' provided, emitting code for the dynamic loader
[info...] bsim6MOD.core.cpp and bsim6MOD.core.h: files created
[info...] bsim6MOD.defs.h: file created
[info...] bsim6MOD.analogfunction.h created
[info...] bsim6MOD.analogfunction.cpp created
[info...] elapsed time: 5 (second)
[info...] admst iterations: 9794271 (9410697 freed)
```

✓ admsXml ✓ Compiler



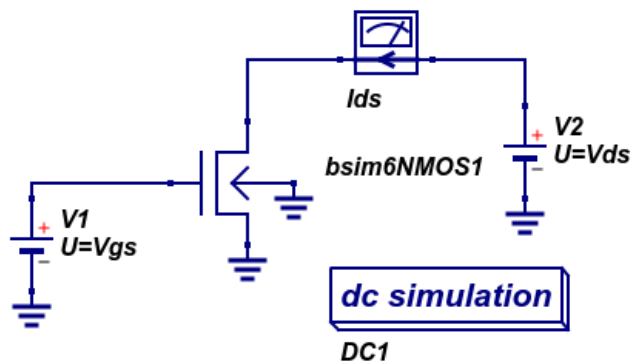


# Qucs experimental implementation of the BSIM 6.1 MOS transistor model

The Qucs Development Team has taken over maintaining the LGPL version of ADMS:  
Latest version is ADMS 2.3.4; <http://sourceforge.net/projects/mot-adms/>  
[Includes contributions from Xyce and WRspice ADMS patches]  
Source code repository has migrated to: <https://github.com/Qucs/ADMS>  
Download : git clone <https://github.com/Qucs/ADMS.git>

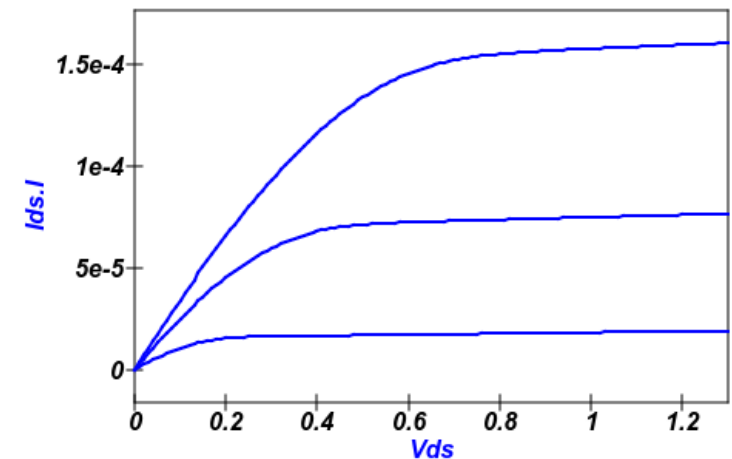
**BSIM 6.1 compiles with ADMS 2.3.4 : Roughly 4000 lines of Verilog-A code generates around 27,000 lines of C++ code for compiling and linking to Qucs 0.0.18**

**Examples of initial test results for the Qucs version of a BSIM 6.1 MOS n and p devices: the new implementation is currently under test and will be published once the Qucs “Development Team” is satisfied that it functions correctly and accurately. Likely publication will be with the release of the next Qucs snapshot.**

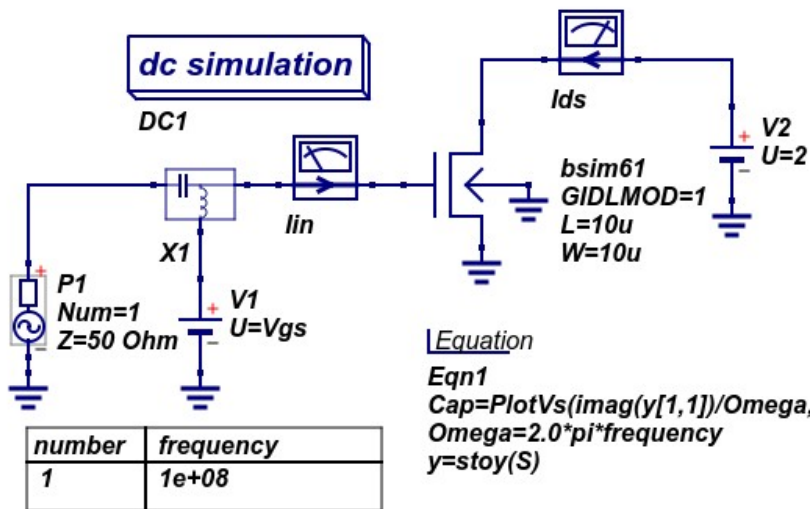


**Parameter sweep**  
SW2  
Sim=SW1  
Type=lin  
Param=Vgs  
Start=0.4  
Stop=1.0  
Points=3

**Parameter sweep**  
SW1  
Sim=DC1  
Type=lin  
Param=Vds  
Start=0  
Stop=1.3  
Points=131



# Qucs experimental implementation of the BSIM 6.1 MOS transistor model : continued



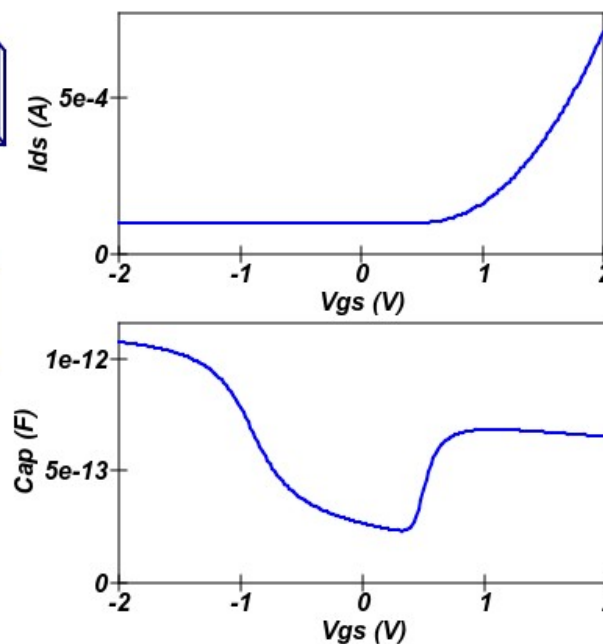
Equation  
Eqn1  
Cap=PlotVs(imag(y[1,1])/Omega, Vgs)  
Omega=2.0\*pi\*frequency  
y=stoy(S)

S parameter simulation

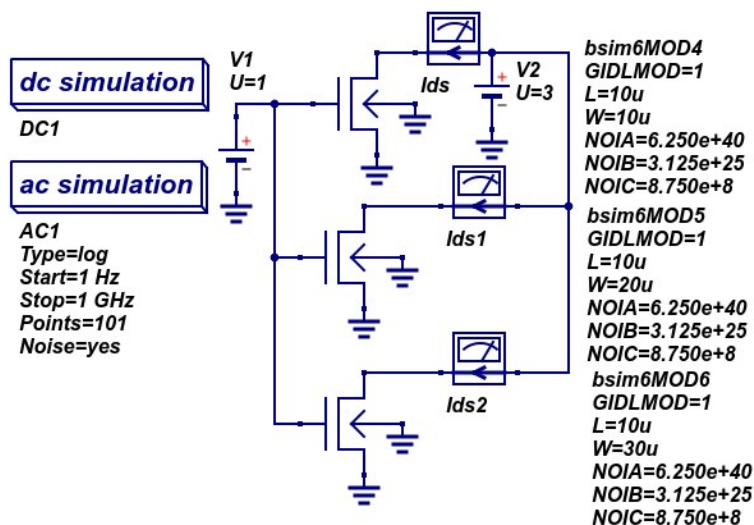
SP1  
Type=const  
Values=[1e8]

Parameter sweep

SW2  
Sim=SP1  
Type=lin  
Param=Vgs  
Start=-2  
Stop=2  
Points=201



Please note these simulation results are currently being checked and may not be accurate

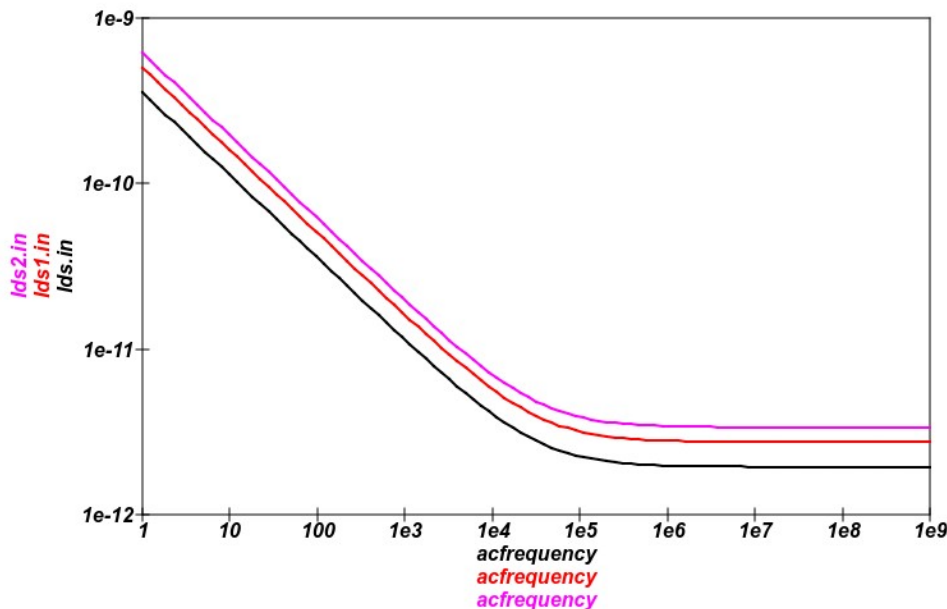


dc simulation

DC1

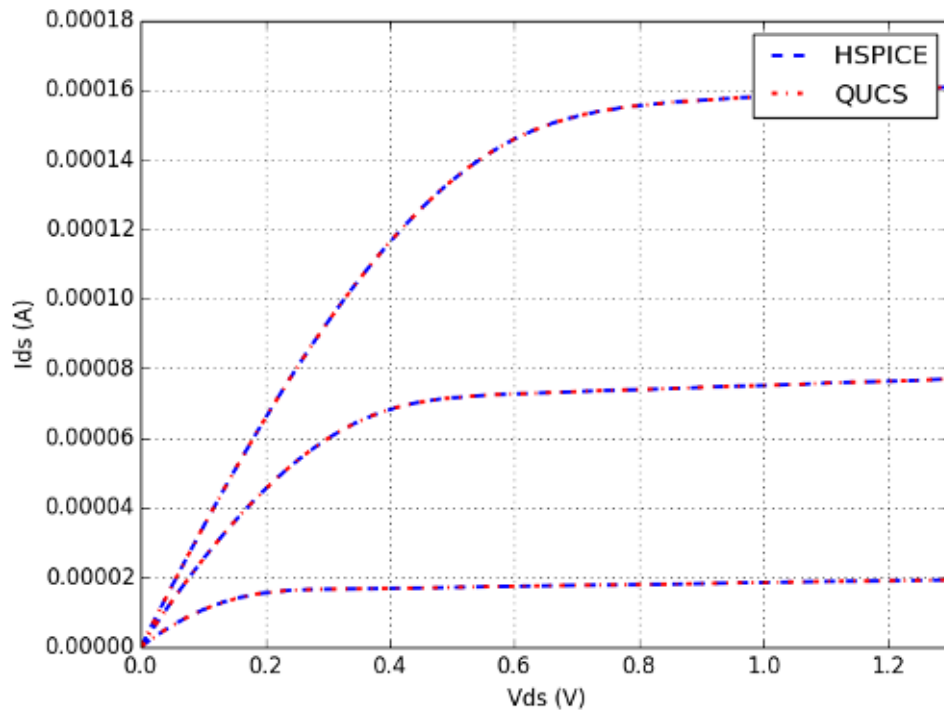
ac simulation

AC1  
Type=log  
Start=1 Hz  
Stop=1 GHz  
Points=101  
Noise=yes

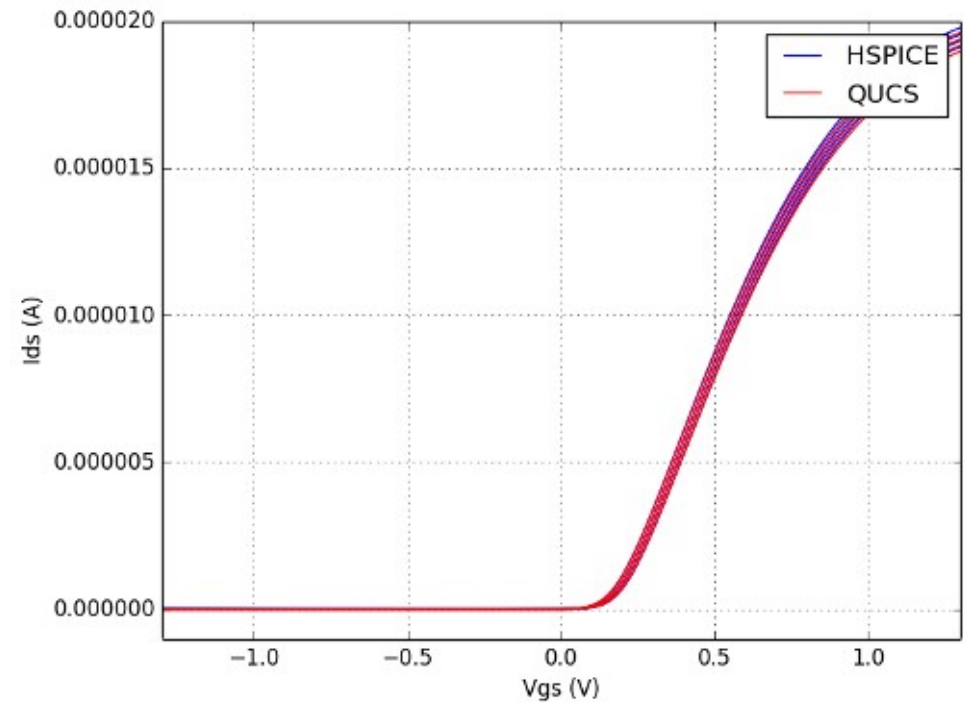


# Qucs experimental implementation of the BSIM 6.1 MOS transistor model : continued

Qucs/ HSPICE: comparison of simulated nMOS I/V characteristics



$I_{ds}$ (A) against  $V_{ds}$ (V)



$I_{ds}$ (A) against  $V_{gs}$ (V)



# Qucs experimental implementation of the BSIM 6.1 MOS transistor model : continued

## Qucs/ HSPICE: comparison of simulated pMOS I/V characteristics

dc simulation

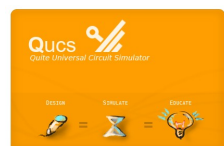
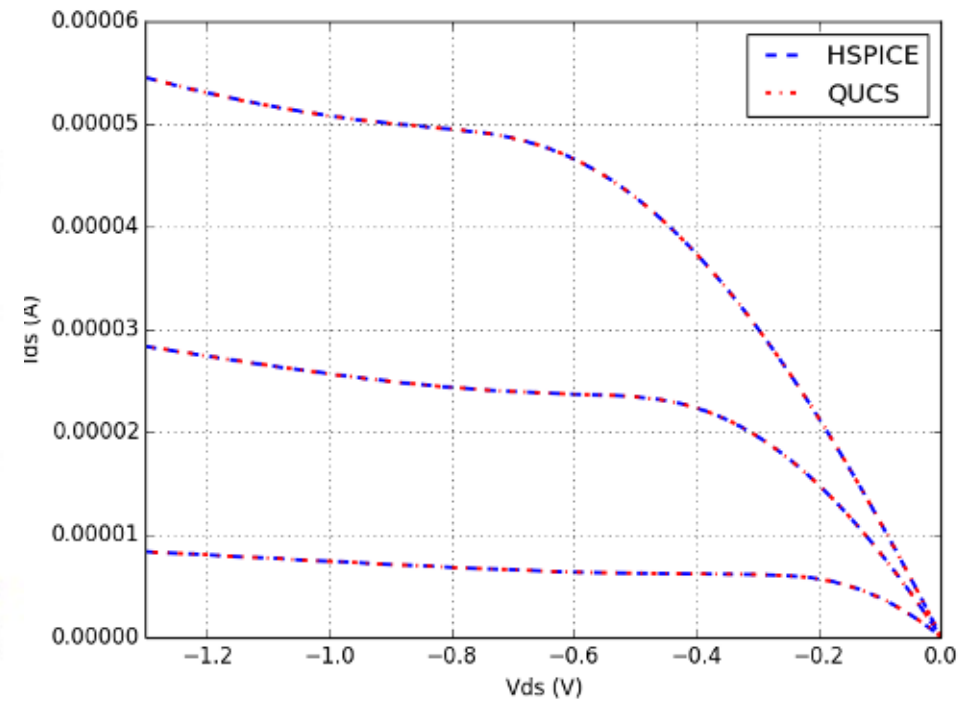
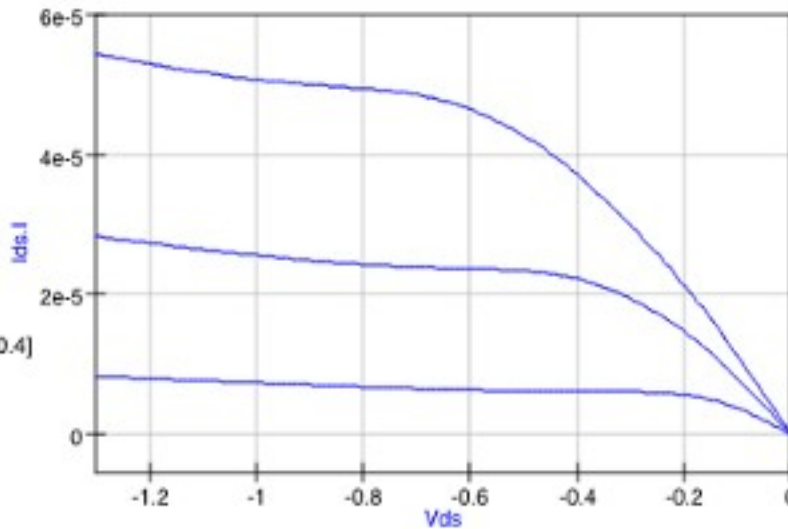
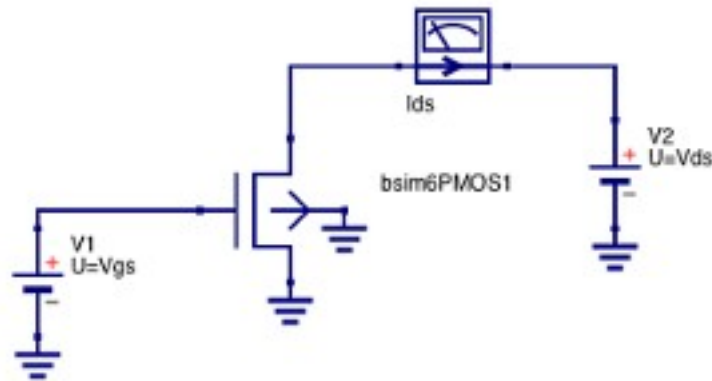
DC1

Parameter sweep

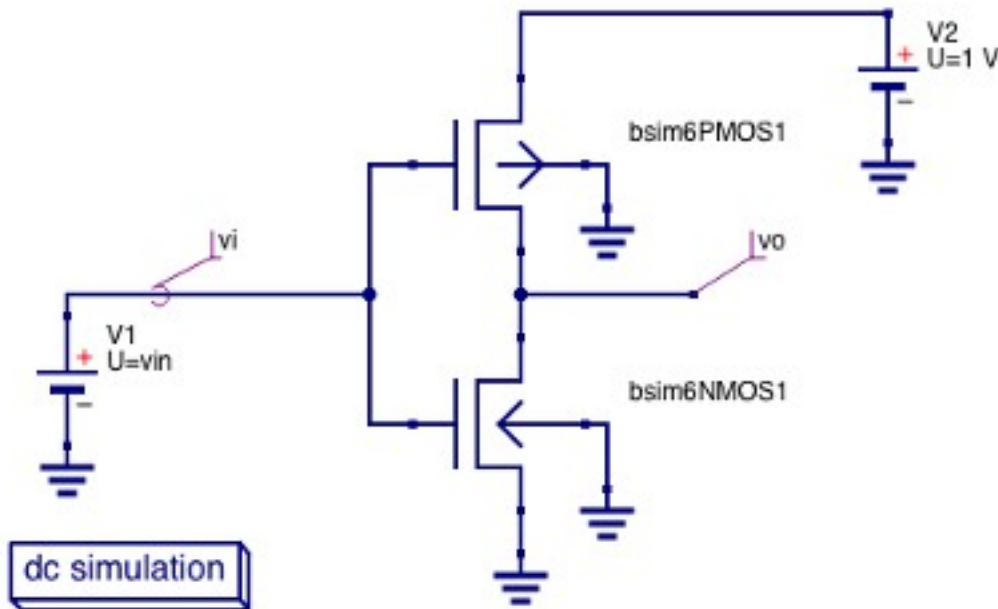
SW1  
Sim=DC1  
Type=In  
Param=Vds  
Start=0  
Stop=-1.3  
Points=131

Parameter sweep

SW2  
Sim=SW1  
Type=lst  
Param=Vgs  
Values=[-1.0; -0.7; -0.4]



# Qucs experimental implementation of the BSIM 6.1 MOS transistor model : continued

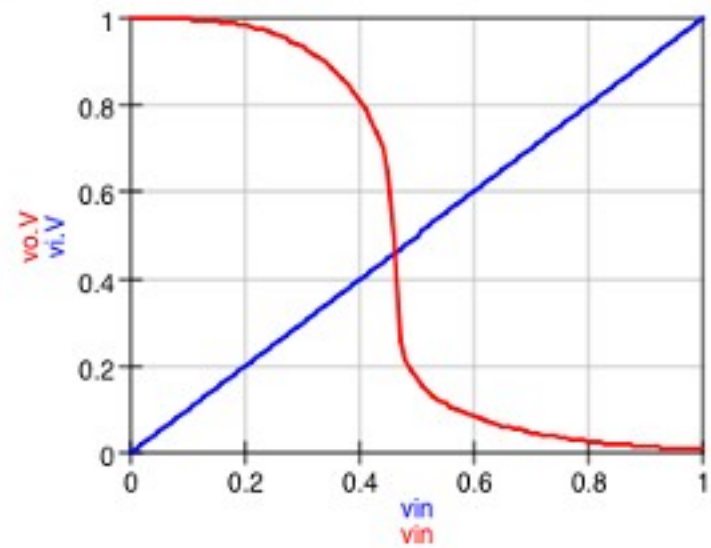


dc simulation

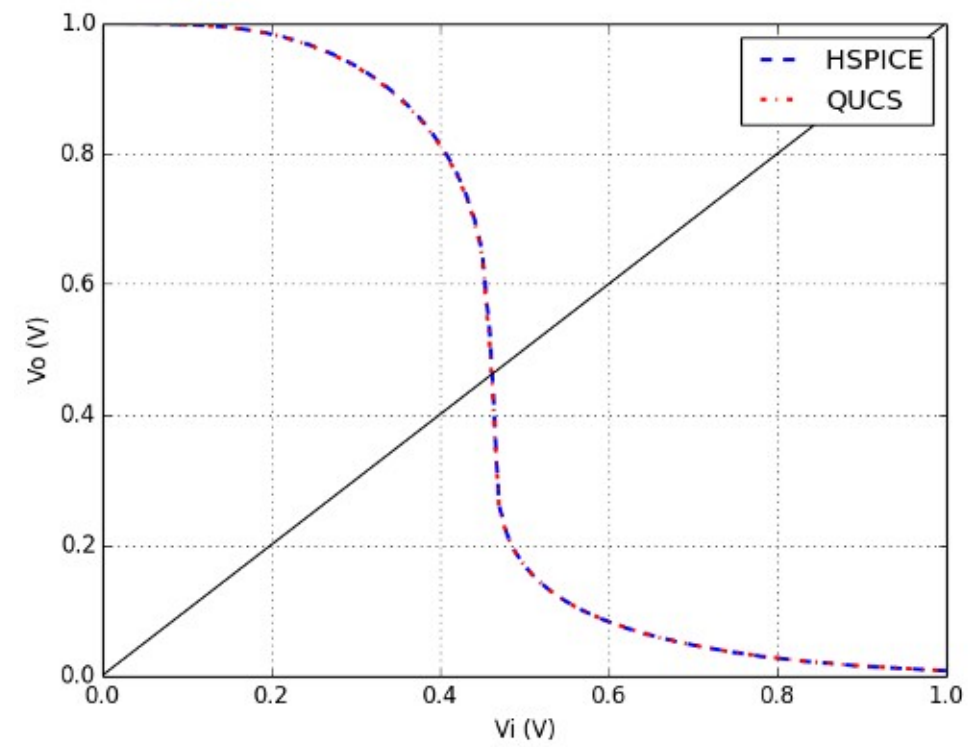
DC1

Parameter sweep

SW1  
 Sim=DC1  
 Type=lin  
 Param=vin  
 Start=0  
 Stop=1  
 Points=101

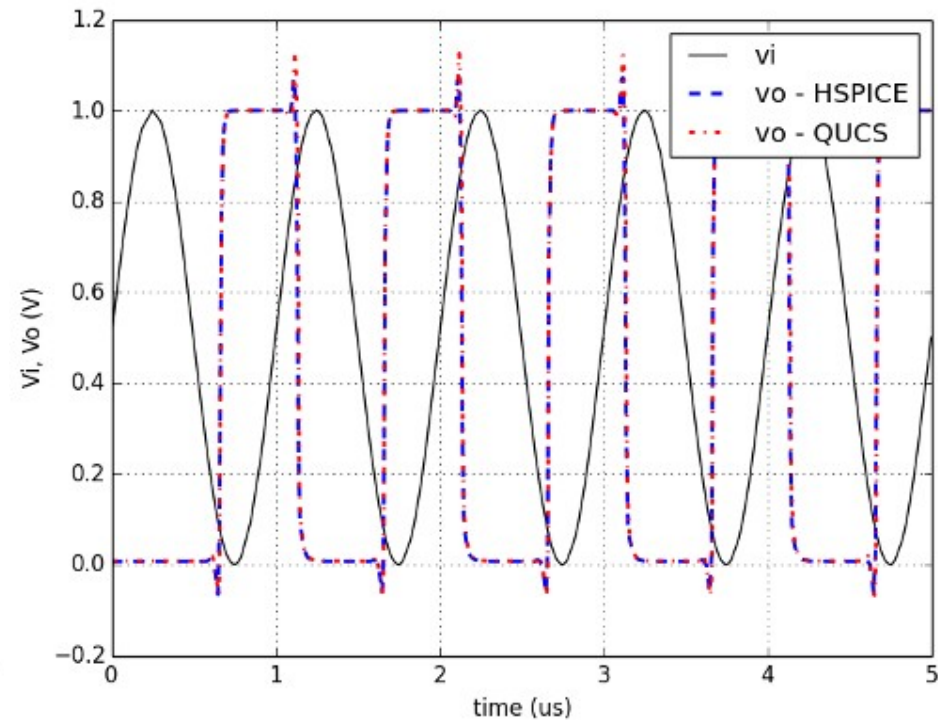
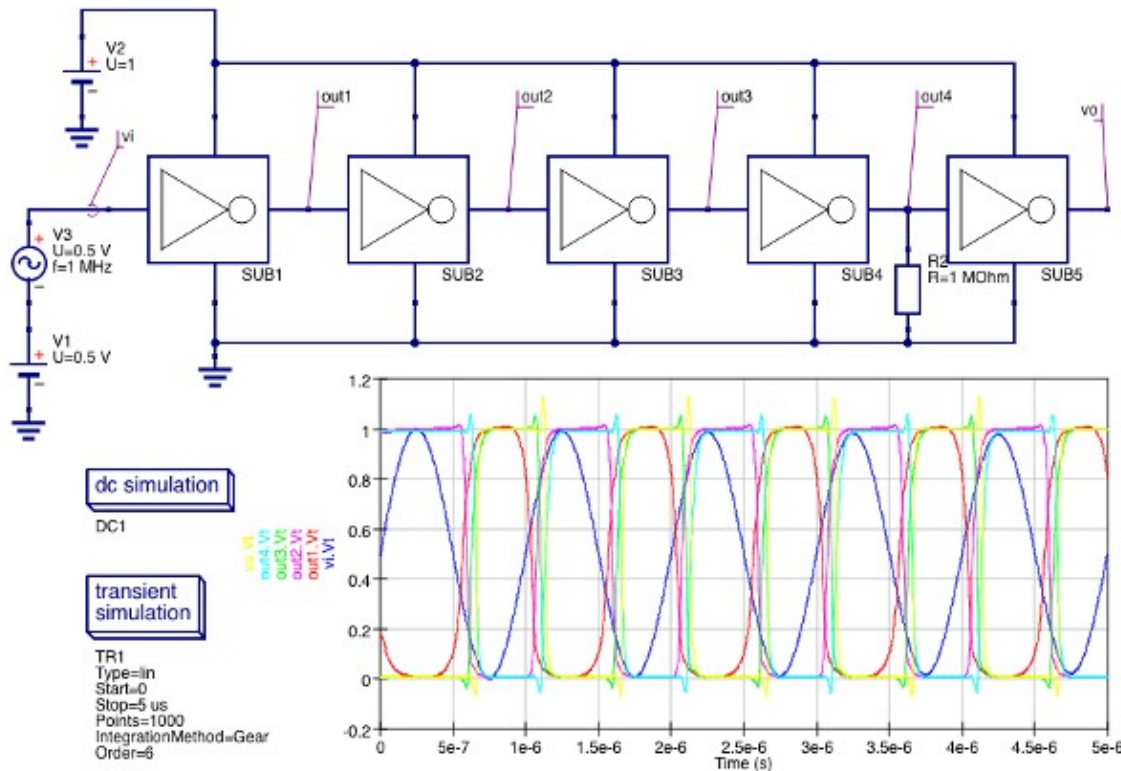


## Qucs/ HSPICE: comparison of simulated CMOS inverter characteristics



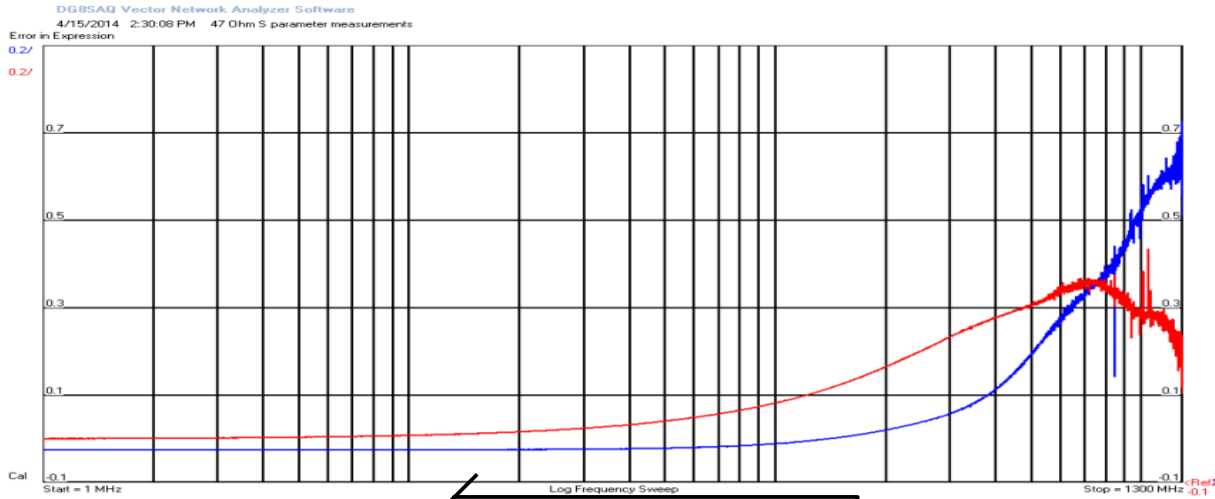
# Qucs experimental implementation of the BSIM 6.1 MOS transistor model : continued

## Qucs/ HSPICE: comparison of simulated CMOS inverter transient characteristics



NOTE: resistor R2 has been added to the original HSPICE test circuit to aid DC convergence.

# Model parameter extraction: linking Qucs with low-cost measurement instrumentation; RF components



Measured S parameters

Qucs device model parameter extraction system: Mike Harrison, April 2014 – RF RESISTOR MODEL Version 0.0.4

**Optimization**

Opt1

Equation

Eqn3

$$Cf1=A*(\text{real}(S[2,2])-\text{real}(S[1,1]))^2$$

$$Cf2=B*(\text{imag}(S[2,2])-\text{imag}(S[1,1]))^2$$

**S parameter simulation**

SP1

Type=log

Start=1e6

Stop=1.3e9

Points=1501

Simulation Controls

**Test circuits**

**Measurements**

**Simulation**

Equation

Eqn1	Eqn4	Eqn5
Zr=real(stoz(S))	A=1	Sr_1=real(S[1,1])
Zi=imag(stoz(S))	Rm=47.3	Si_1=imag(S[1,1])
	B=1	Sr_2=real(S[2,2])
		Si_2=imag(S[2,2])

Optimized values of model parameters are listed by displaying Optimization icon menu "Variables"

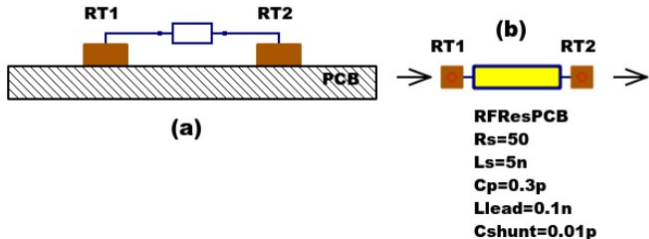
ASCO optimization

Verilog-A model

```

include "disciplines.vams"
include "constants.vams"
module RFResPCB(RT1, RT2);
inout RT1, RT2; electrical n1, n2, n3, nx, ny, nz;
define attr(txt) (*txt*)
parameter real Rs = 50 from [1e-20 : inf]
  attr(info="RF resistance" unit="Ohm's");
parameter real Cp = 0.3e-12 from [0 : inf]
  attr(info="Resistor shunt capacitance" unit="F");
parameter real Ls = 8.5e-9 from [1e-20 : inf]
  attr(info="Series inductance" unit="H");
parameter real Llead = 0.1e-9 from [1e-20 : inf]
  attr(info="Parasitic lead inductance" unit="H");
parameter real Cshunt = 1e-10 from [1e-20 : inf]
  attr(info="Parasitic shunt capacitance" unit="F");
parameter real Tc1 = 0.0 from [-100 : 100]
  attr(info="First order temperature coefficient" unit="Ohm/Celsius");
parameter real Tc2 = 0.0 from [-100 : 100]
  attr(info="Second order temperature coefficient" unit="(Ohm/Celsius)^2");
parameter real Tnom = 26.85 from [-273.15 : 300]
  attr(info="Parameter extraction temperature" unit="Celsius");
parameter real Temp = 26.85 from [-273.15 : 300]
  attr(info="Simulation temperature" unit="Celsius");
branch (RT1, n1) bRT1n1; branch (n1, n2) bn1n2;
branch (n1, n3) bn1n3; branch (n2, n3) bn2n3;
branch (n3, RT2) bn3RT2;
real Rst, FourKT, n, Tdiff, Rn;
analog begin
@ (initial_model) begin
  Tdiff = Temp-Tnom; FourKT = 4.0*P_K*Temp;
  Rst = Rs*(1.0+Tc1*Tdiff+Tc2*Tdiff*Tdiff);
  Rn = FourKT/Rst;
end
I(n1) <+ ddt(Cshunt*V(n1)); I(bn1n2) <+ V(bn1n2)/Rst;
I(bn1n3) <+ ddt(Cp*V(bn1n3)); I(n3) <+ ddt(Cshunt*V(n3));
I(bRT1n1) <+ -V(nx); I(nx) <+ V(bRT1n1);
I(nx) <+ ddt(Llead*V(nx));
I(bn2n3) <+ -V(ny); I(ny)
<+ V(bn2n3); I(ny)
<+ ddt(Ls*V(ny)); I(bn3RT2) <+ -V(nz);
I(nz) <+ V(bn3RT2);
I(nz)n <+ ddt(Llead*V(nz));
I(bn1n2) <+ white_noise(Rn, "thermal");
end
endmodule
  
```

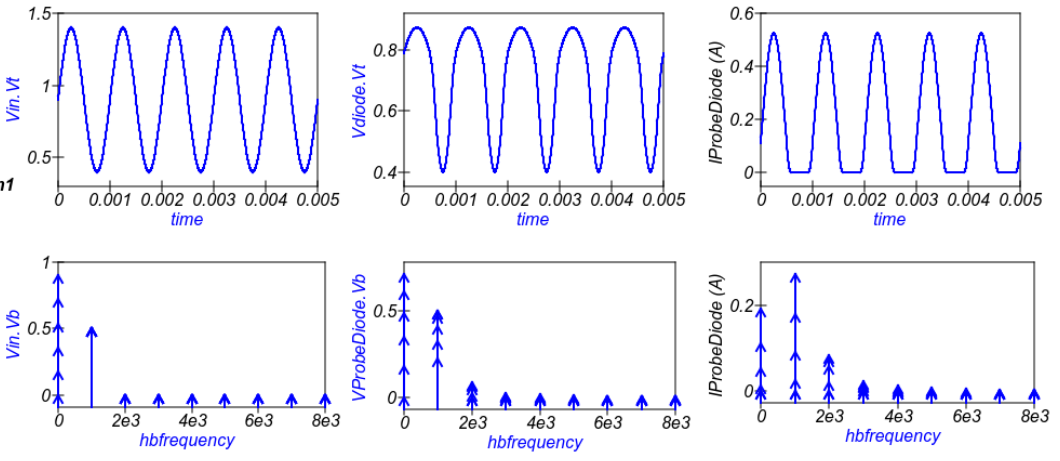
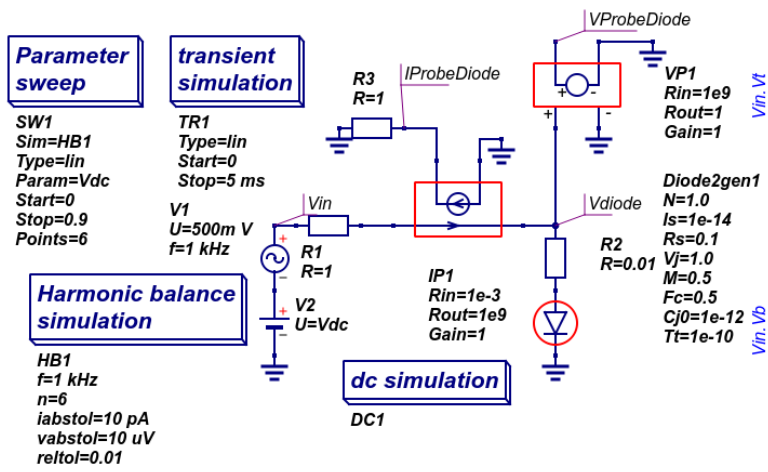
Verilog-A model code



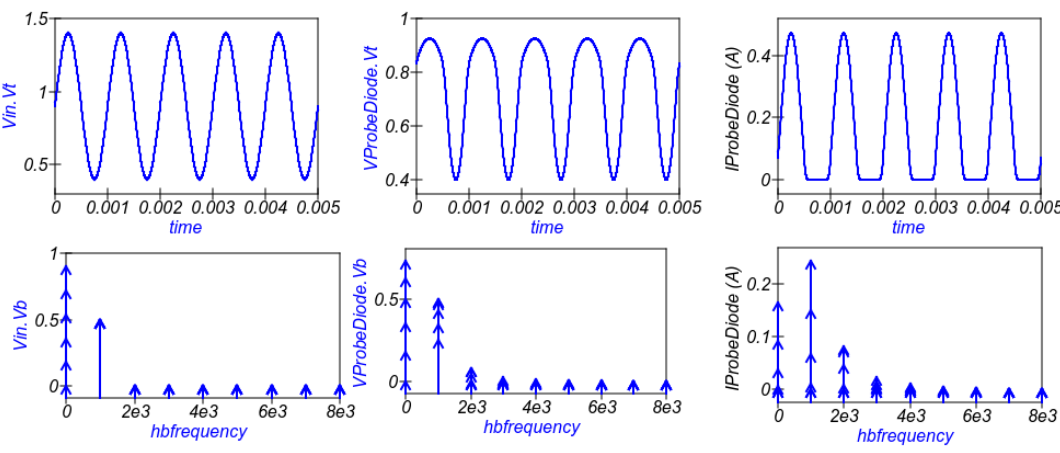
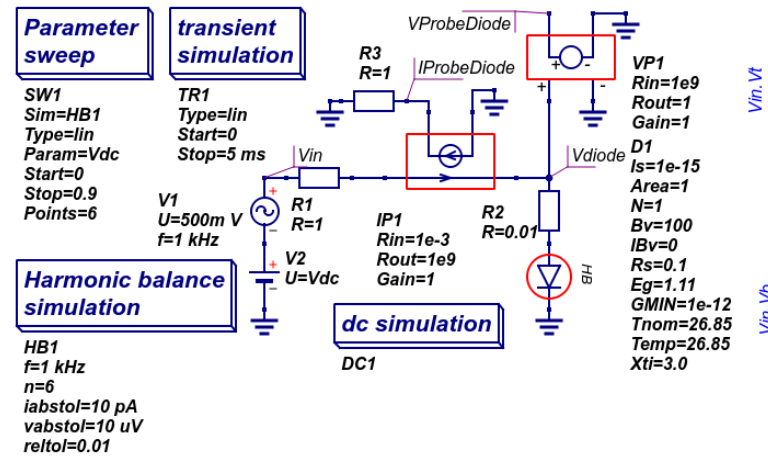
DG8SAQ VNWA 3 & 3E- Vector Network Analysers, SDR Kits Limited, Grangeside Business Centre, 129 Devizes Road, Trowbridge, Wilts BA14-7sZ, United Kingdom, 2014. www.SDR-Kits.net.

# Qucs swept Harmonic Balance simulation: Verilog-A and EDD diode models

## Verilog-A diode model



## EDD diode model





# Current and possible future directions for Qucs development

## Current projects

- Finish Qt3 to Qt4 port.
- Continue development of the Qucs “Turn-key” Verilog-A modelling system.
- Improve Qucs simulation engines: particularly transient and Harmonic Balance simulation code.
- Improve the Qucs/Octave interface.
- Improve the Qucs/Python interface and continue work on high quality post simulation data visualisation capabilities.
- Add more industrial standard compact semiconductor device models to Qucs.
- Continue development of Qucs RF component models and macromodels.
- Continue work on device model parameter extraction.

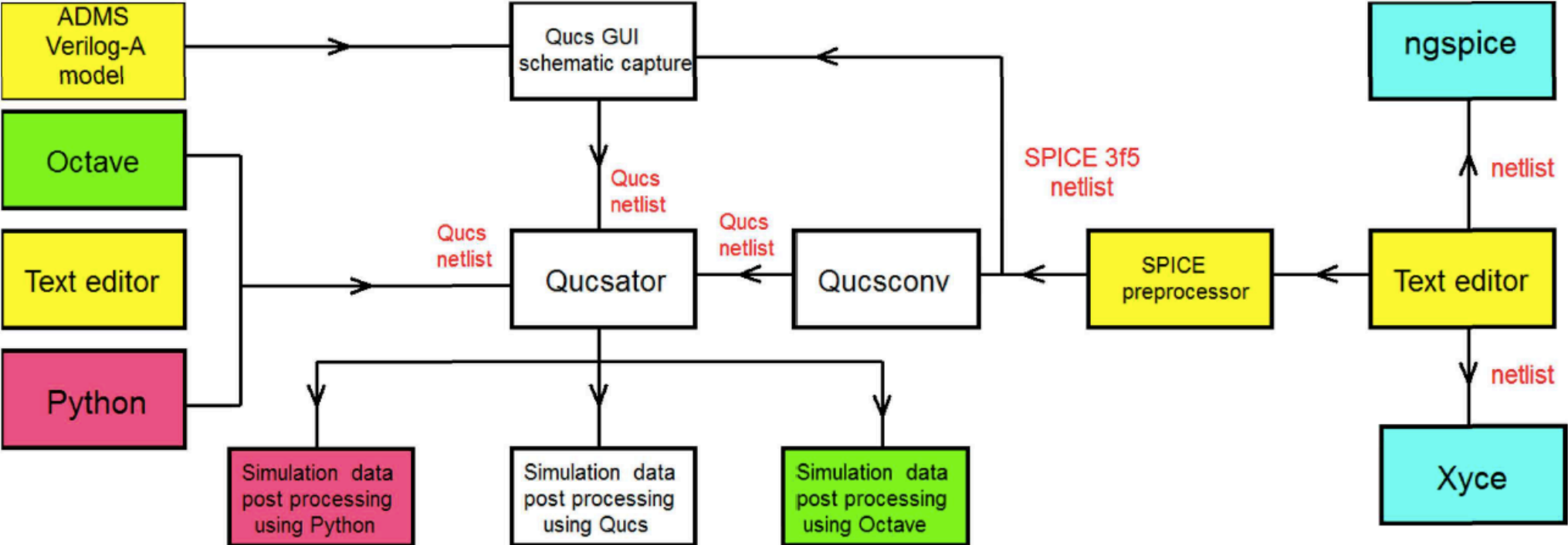
## Future projects

- Collect ideas from (1) the Qucs development team and (2) the Qucs user community.
- Update the Qucs project roadmap as a guide to future developments.
- Implement agreed roadmap in a structured way.

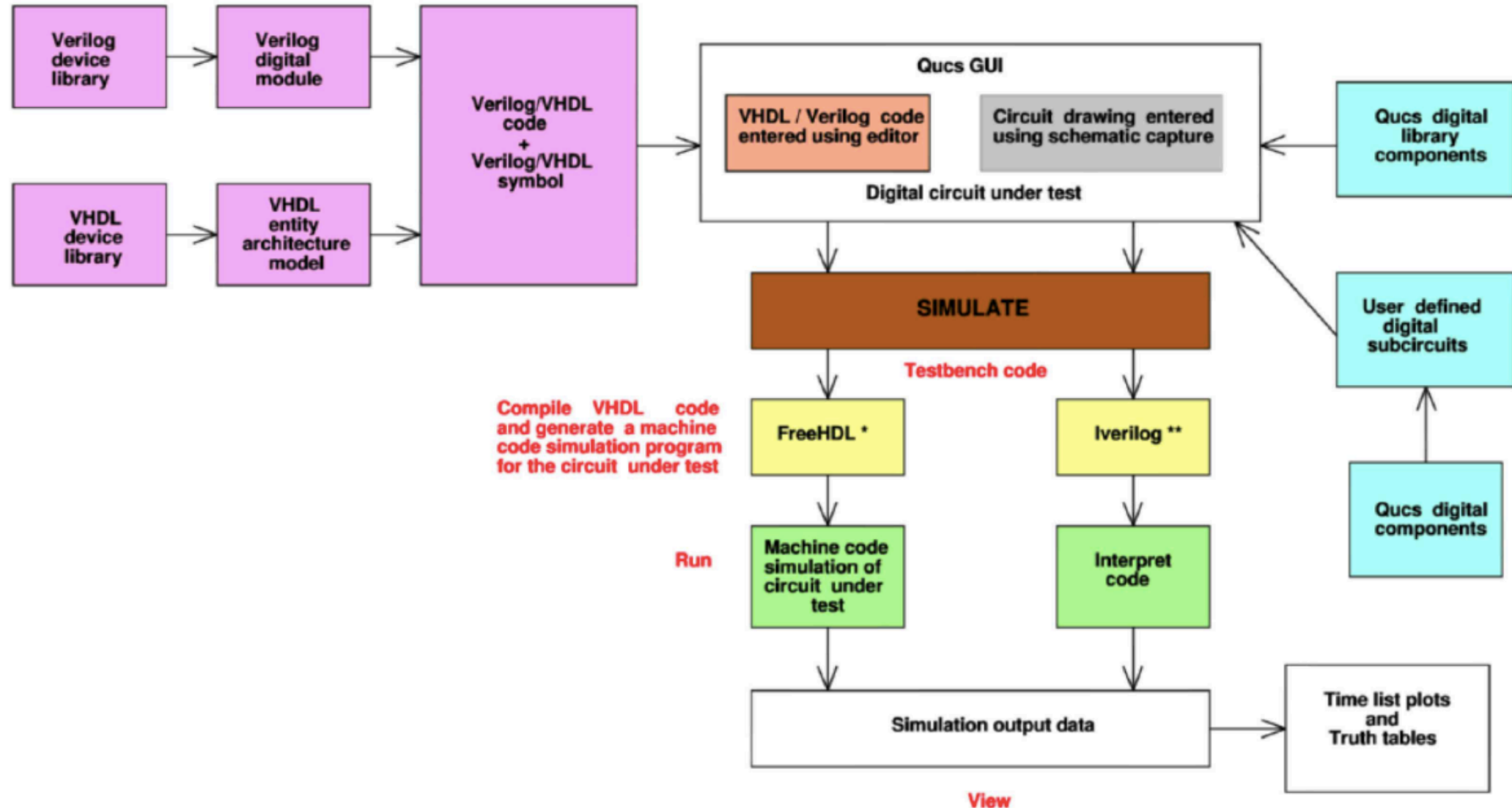


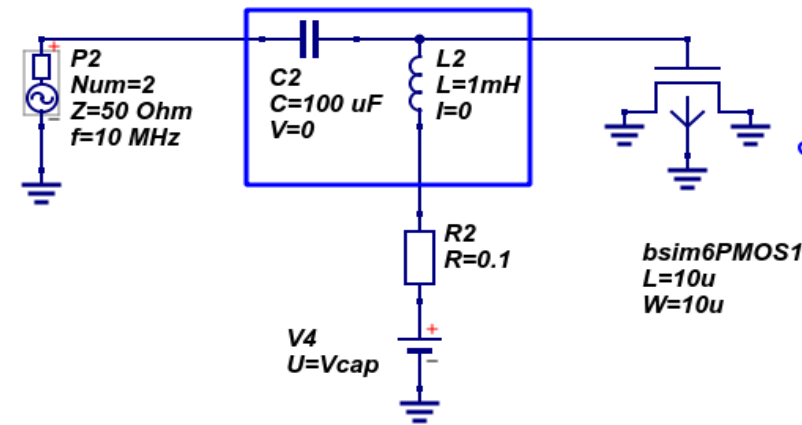
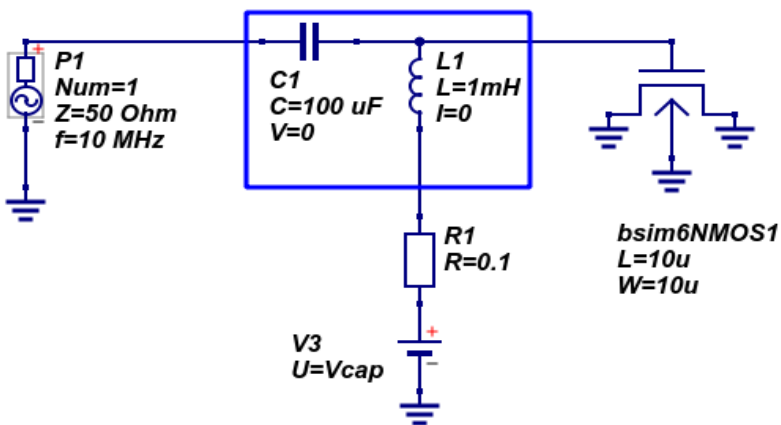
Backup

# Qucs package: Analogue Simulator Structure



# Qucs Digital Simulation Capabilities





Equation

Eqn2  
 $y = \text{stoy}(S)$   
 $\Omega = 2 * \pi * \text{frequency}$   
 $\text{Capn} = \text{PlotVs}(\text{imag}(y[1,1]/\Omega), V_{\text{cap}})$   
 $\text{Capp} = \text{PlotVs}(\text{imag}(y[2,2]/\Omega), V_{\text{cap}})$

dc simulation

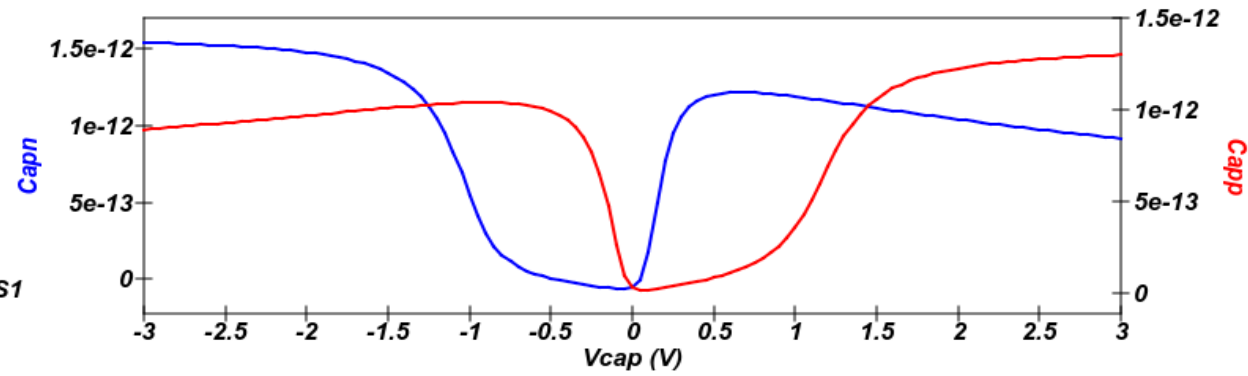
DC1

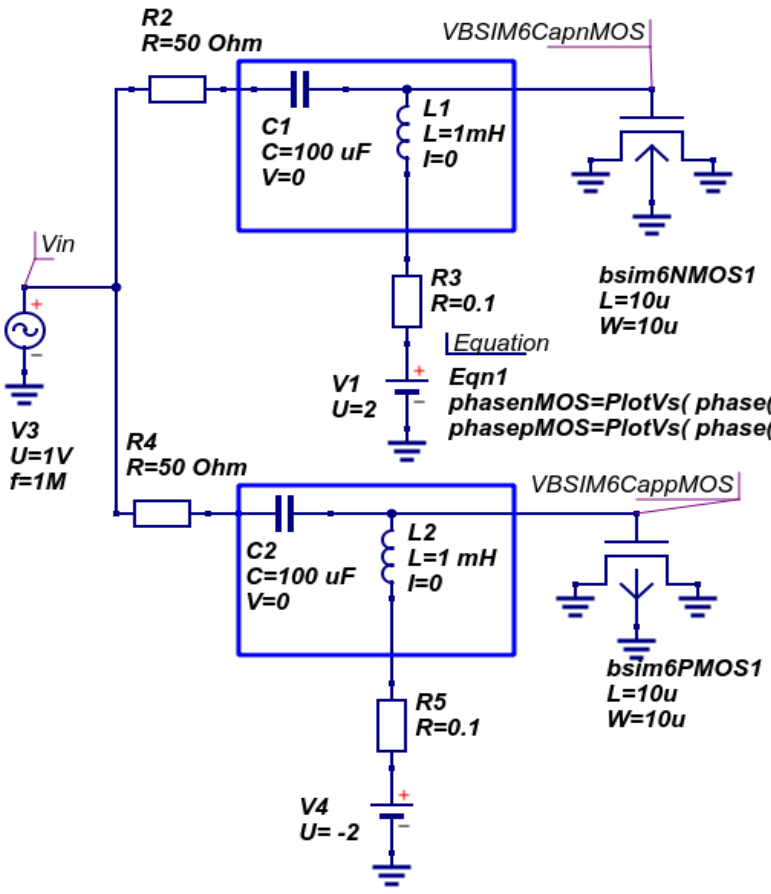
S parameter simulation

SP1  
 Type=const  
 Values=[10 M]

Parameter sweep

SW1  
 Sim=SP1  
 Type=lin  
 Param=Vcap  
 Start=-3  
 Stop=+3  
 Points=121



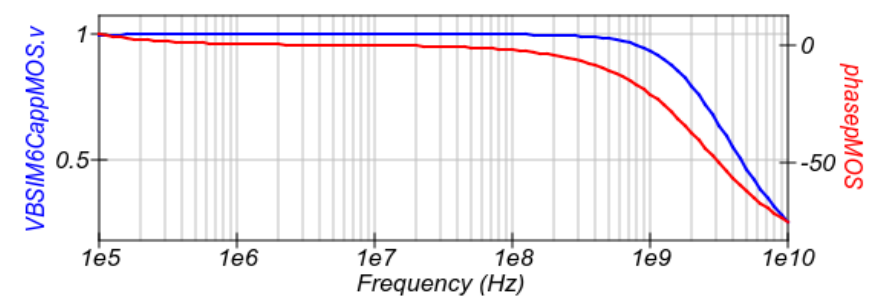
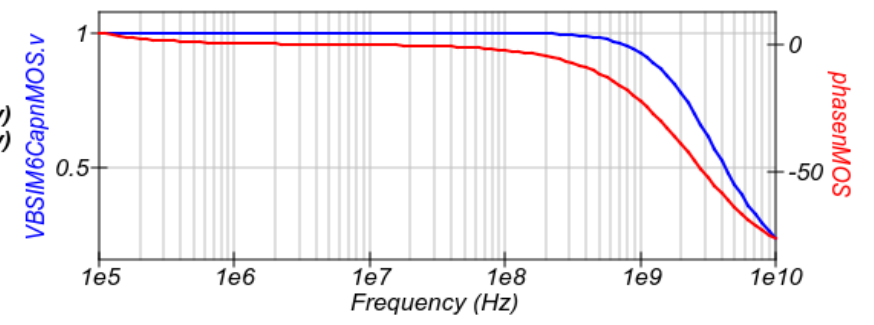
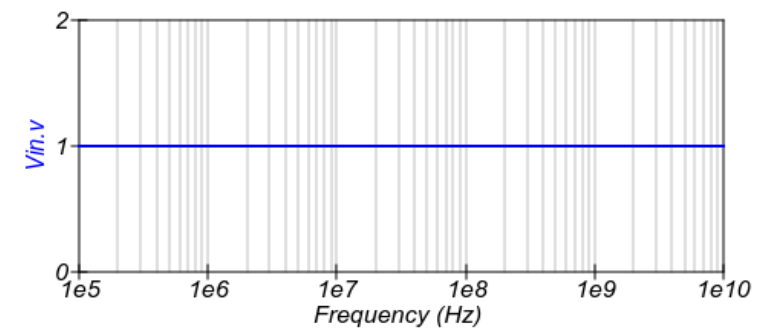


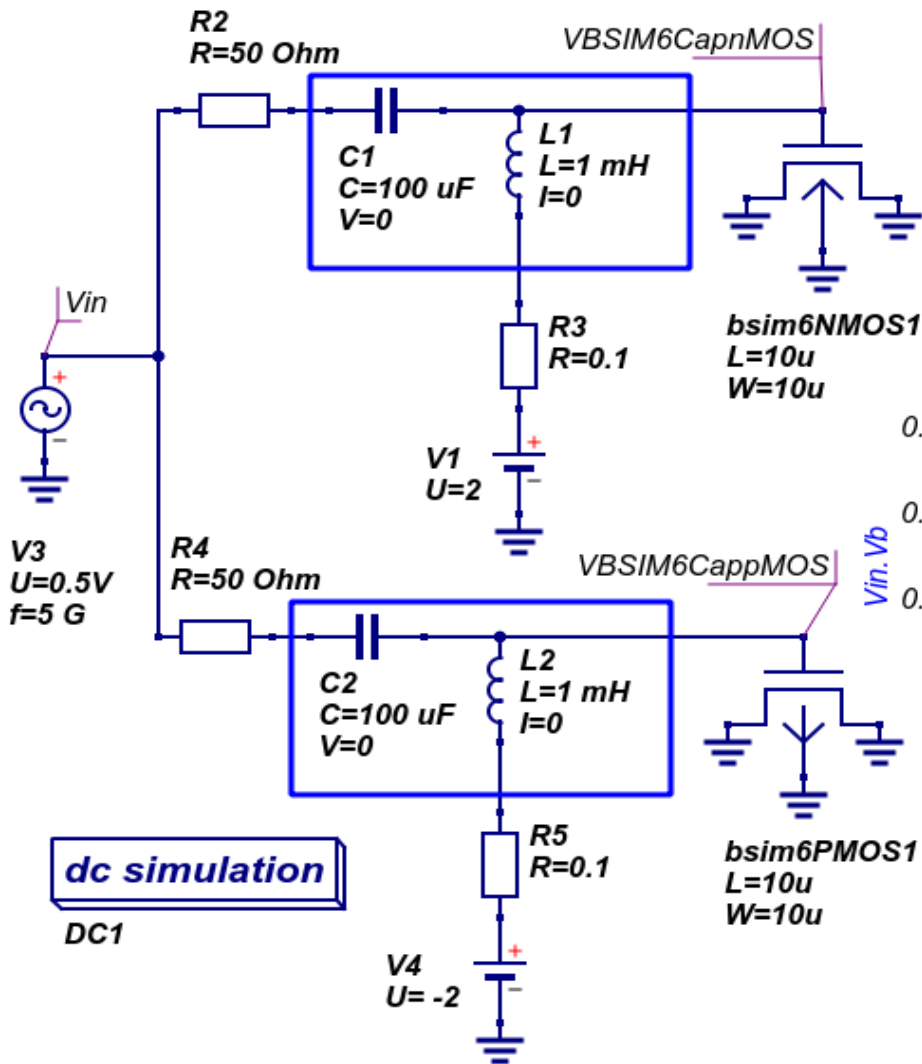
**ac simulation**

**AC1**  
 Type=log  
 Start=0.1M Hz  
 Stop=10 GHz  
 Points=101

**dc simulation**

**DC1**



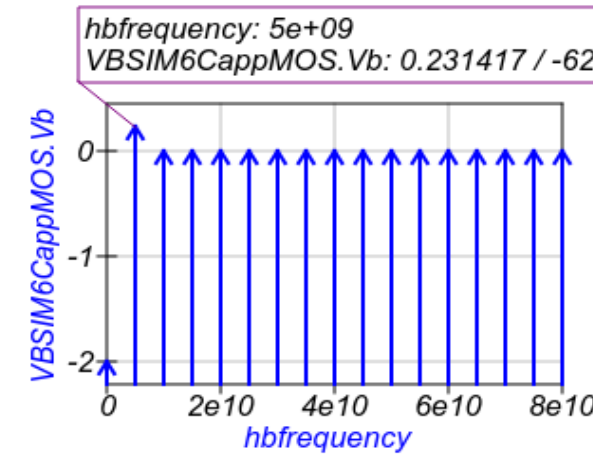
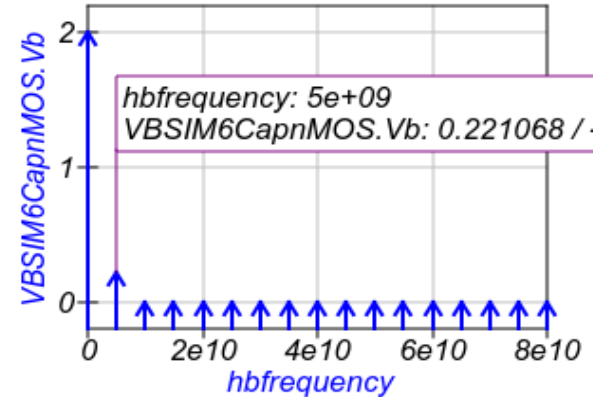
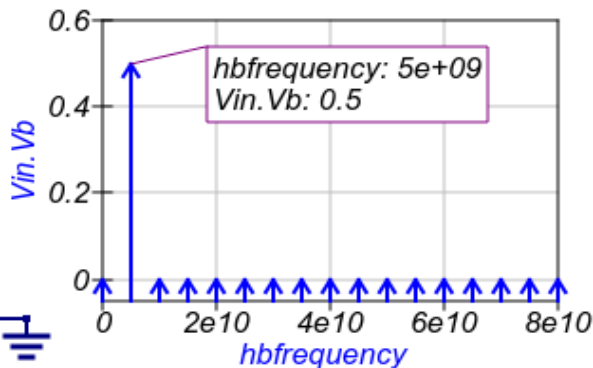


**Harmonic balance simulation**

HB1  
 f=5 G  
 n=12  
 iabstol=10 pA  
 vabstol=10 uV  
 reltol=0.01  
 MaxIter=150

**dc simulation**

DC1



**NOTE: AC input is 0.5V peak.**